
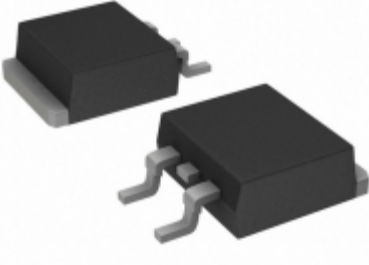







	<h2 style="color: red;">FQB3N25TM</h2> <p>Hersteller-Teilenummer: FQB3N25TM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 250V 2.8A D2PAK</p> <p>Datenblätter:  FQB3N25TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34333 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB3N25TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 250V 2.8A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34333 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.8A (Tc)
Rds On (Max) @ Id, Vgs	2.2 Ohm @ 1.4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	170pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB3N25TM ist neu im Original, Suche FQB3N25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3N25TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3N25TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB34P10TM-F085P AMI Semiconductor / ON Semiconductor PMOS D2PAK 100V 60 MOHM</p>	 <p>FQB3N25 VB FQB3N25 VB</p>	 <p>FQB3N40TM Fairchild/ON Semiconductor MOSFET N-CH 400V 2.5A D2PAK</p>	 <p>FQB3N30TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 300V 3.2A D2PAK</p>
 <p>FQB34P10TM_F085 Fairchild/ON Semiconductor FQB34P10TM_F085 Fairchild/ON Semiconductor</p>	 <p>FQB3N30TM Fairchild/ON Semiconductor MOSFET N-CH 300V 3.2A D2PAK</p>	 <p>FQB3N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 2.8A D2PAK</p>	 <p>FQB3N40TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 2.5A D2PAK</p>

heiße Teile

Mehr

 FQB32N12V2	 FQB32N12V2TM	 FQB32N12V2TM	 FQB32N20	 FQB32N20C
 FQB32N20CTM	 FQB32N20CTM	 FQB32N30	 FQB33N10	 FQB33N10L
 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM	 FQB33N10TM	 FQB34N20
 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002
 FQB34P10	 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM
 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM	 FQB3N60C
 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM	 FQB3P20TM
 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10	 FQB44N10TM
 FQB44N10TM	 FQB46N15	 FQB46N15TM	 FQB47P06	 FQB47P06TM
 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM	 FQB4N20TM

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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